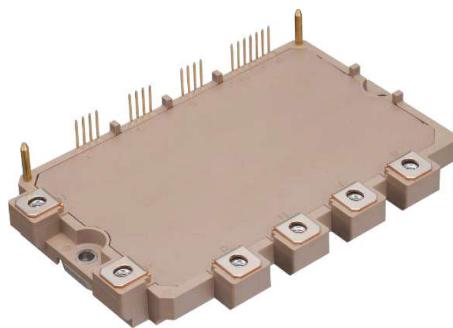
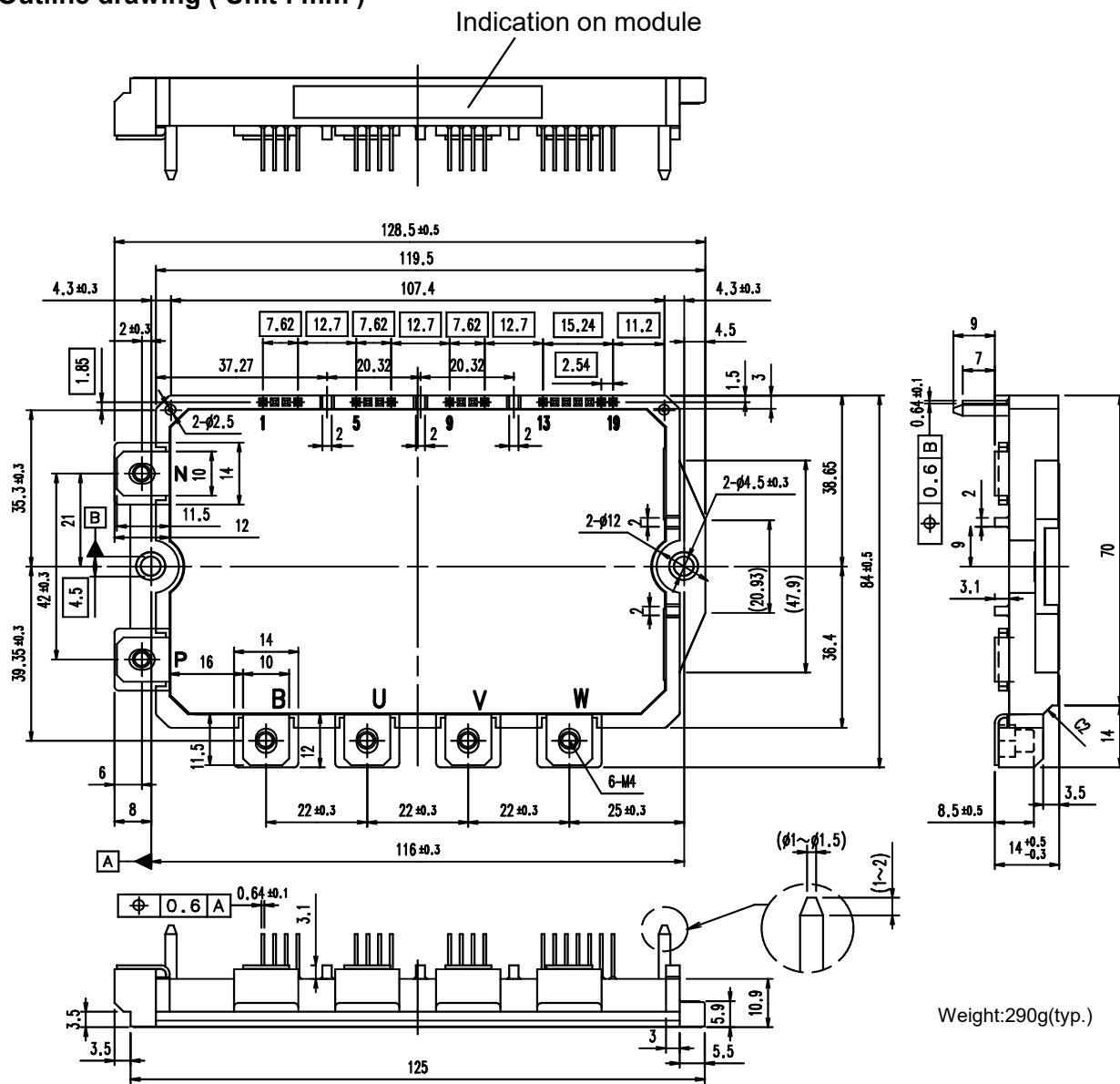


# 7MBP150XDN120-50

**IGBT Modules**
**IGBT Module (X series)**  
**1200V / 150A / IPM**
**■ Features**

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit


**■ Outline drawing ( Unit : mm )**


# 7MBP150XDN120-50

IGBT Modules

## ■ Absolute maximum ratings

$T_C=25^\circ\text{C}$ ,  $T_{vj}=25^\circ\text{C}$ ,  $V_{CC}=15\text{V}$  unless otherwise specified

Items	Symbol	Conditions	Min.	Max.	Units	
Collector-Emitter voltage	$V_{CES}$	*1	-	1200	V	
Short circuit voltage	$V_{SC}$	*2	400	800	V	
Inverter Collector current	$I_C$	DC	-	150	A	
	$I_{CP}$	1ms	-	300	A	
	$-I_C$	Duty=100% *3	-	150	A	
Total power dissipation	$P_{tot}$	IGBT 1 device *4	-	882	W	
Brake	Repetitive peak reverse voltage	$V_{RRM}$	Diode part	-	1200	V
	Collector current	$I_C$	DC	-	75	A
		$I_{CP}$	1ms	-	150	A
	Forward current of diode	$I_F$		-	75	A
Total power dissipation	$P_{tot}$	IGBT 1 device *4	-	416	W	
Supply voltage of pre-driver	$V_{CC}$	*5	-0.5	20	V	
Input signal voltage	$V_{in}$	*6	-0.5	$V_{CC}+0.5$	V	
Alarm signal voltage	$V_{ALM}$	*7	-0.5	$V_{CC}$	V	
Alarm signal current	$I_{ALM}$	*8	-	20	mA	
Virtual junction temperature	$T_{vj}$		-	175	°C	
Operating virtual junction temperature	$T_{vjop}$		-	150	°C	
Operating case temperature	$T_c$		-20	125	°C	
Storage temperature	$T_{stg}$		-40	125	°C	
Solder temperature	$T_{sol}$	*9	-	260	°C	
Isolating voltage	$V_{isol}$	*10	-	AC2500	Vrms	
Mounting torque of screws to heat sink	$M_s$	Mounting(M4)	-	1.7	Nm	
Mounting torque of screws to terminals	$M_t$	Main terminals(M4)	-	1.7	Nm	

### Notes

\*1:  $V_{CES}$  shall be applied to the input voltage between terminal P-(U,V, W) and (U,V, W,B)-N.

\*2: In the case of the load inductance to be over 1μH.

\*3: Duty=150°C/ $R_{th(j-c)D}/(I_F \times V_F$  Max.)×100

\*4:  $P_{tot}=150°C/R_{th(j-c)Q}$

\*5:  $V_{CC}$  shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9,14 and 13.

\*6:  $V_{in}$  shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9,15~18 and 13.

\*7:  $V_{ALM}$  shall be applied to the voltage between terminal No.2 and 1 , 6 and 5 , 10 and 9 , 19 and 13.

\*8:  $I_{ALM}$  shall be applied to the input current to terminal No.2,6,10 and 19.

\*9: Immersion time 10±1sec. 1 time.

\*10: Terminal to base, 50/60Hz sine wave 1 min. All terminals should be connected together during the test.

# 7MBP150XDN120-50

IGBT Modules

## ■ Electrical characteristics

### ● Main circuit

 $T_{vj}=25^\circ\text{C}$ ,  $V_{CC}=15\text{V}$  unless otherwise specified

	Item	Symbol	Conditions		Min.	Typ.	Max.	Units
Inverter	Collector current at off signal input	$I_{CES}$	$V_{CE} = 1200\text{V}$		-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 150\text{A}$	Terminal	-	-	2.20	V
				Chip	-	1.45	-	V
Brake	Forward voltage of FWD	$V_F$	$I_F = 150\text{A}$	Terminal	-	-	2.95	V
				Chip	-	2.15	-	V
	Collector current at off signal input	$I_{CES}$	$V_{CE} = 1200\text{V}$		-	-	1.0	mA
Brake	Collector-Emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 75\text{A}$	Terminal	-	-	2.1	V
				Chip	-	1.7	-	V
	Forward voltage of FWD	$V_F$	$I_F = 75\text{A}$	Terminal	-	-	2.75	V
Switching time *11	$t_{on}$	$I_C = 150\text{A}$	$T_{vj}=150^\circ\text{C}$ $V_{DC}=600\text{V}$	0.5	-	-	0.5	μs
	$t_{d(on)}$			0.5	-	-	0.5	μs
	$t_{off}$			-	-	-	2.0	μs
	$t_{d(off)}$			-	-	-	1.7	μs
	$t_{rr}$	$I_F = 150\text{A}$		-	-	-	0.5	μs

\*11: Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$ 

### ● Control circuit

 $T_{vj}=25^\circ\text{C}$ ,  $V_{CC}=15\text{V}$  unless otherwise specified

	Item	Symbol	Conditions		Min.	Typ.	Max.	Units
Supply current of P-side pre-driver (per one unit)	$I_{cop}$		Switching frequency ( $f_{sw}$ ) = 0~15kHz $T_C = -20\sim125^\circ\text{C}$		-	-	18	mA
	$I_{con}$				-	-	62	mA
Input signal threshold voltage	$V_{inth(on)}$	$V_{in}-\text{GND}$	ON		1.2	1.4	1.6	V
	$V_{inth(off)}$		OFF		1.5	1.7	1.9	V

### ● Protection circuit

 $T_{vj}=25^\circ\text{C}$ ,  $V_{CC}=15\text{V}$  unless otherwise specified

	Item	Symbol	Conditions		Min.	Typ.	Max.	Units
Over current protection level	Inverter	$I_{OC}$	$T_{vj}=150^\circ\text{C}$ Resistance load		225	-	-	A
	Brake				113	-	-	A
Over current protection delay time		$t_{doc}$	$T_{vj}=150^\circ\text{C}$		-	4.0	-	μs
Short circuit protection delay time		$t_{dsc}$	$T_{vj}=150^\circ\text{C}$		-	1.0	-	μs
IGBT chips over heating protection temperature level		$T_{jOH}$	Surface of IGBT chips		175	-	-	°C
Over heating protection hysteresis		$T_{jh}$			-	20	-	°C
Under voltage protection level		$V_{UV}$			11.0	-	12.5	V
Under voltage protection hysteresis		$V_H$			0.2	0.5	-	V
Alarm signal hold time		$t_{ALM(OC)}$	ALM-GND $T_C=-20\sim125^\circ\text{C}$		1.0	2.0	2.4	ms
		$t_{ALM(UV)}$			3.5	4.0	4.5	ms
		$t_{ALM(TjOH)}$			7.0	8.0	9.0	ms
Alarm signal voltage		$V_{ALMH}$	ALM-GND, without protection		14.5	-	15.0	V
Resistance for current limit		$R_{ALM}$			960	-	1570	Ω

# 7MBP150XDN120-50

IGBT Modules

## ■ Thermal resistance characteristics ( $T_c = 25^\circ\text{C}$ )

Item		Symbol	Min.	Typ.	Max.	Units
Thermal resistance junction to case *12	Inverter	$R_{th(j-c)Q}$	-	-	0.17	K/W
		$R_{th(j-c)D}$			0.27	K/W
	Brake	$R_{th(j-c)Q}$	-	-	0.36	K/W
		$R_{th(j-c)D}$	-	-	0.56	K/W
Thermal resistance case to heat sink *13		$R_{th(c-s)}$	-	0.05	-	K/W

\*12: For 1 device , the measurement point of the case is just under the chip.

\*13: This is the value which is defined mounting on the additional heat sink with 1 W/(m·K) thermal grease.

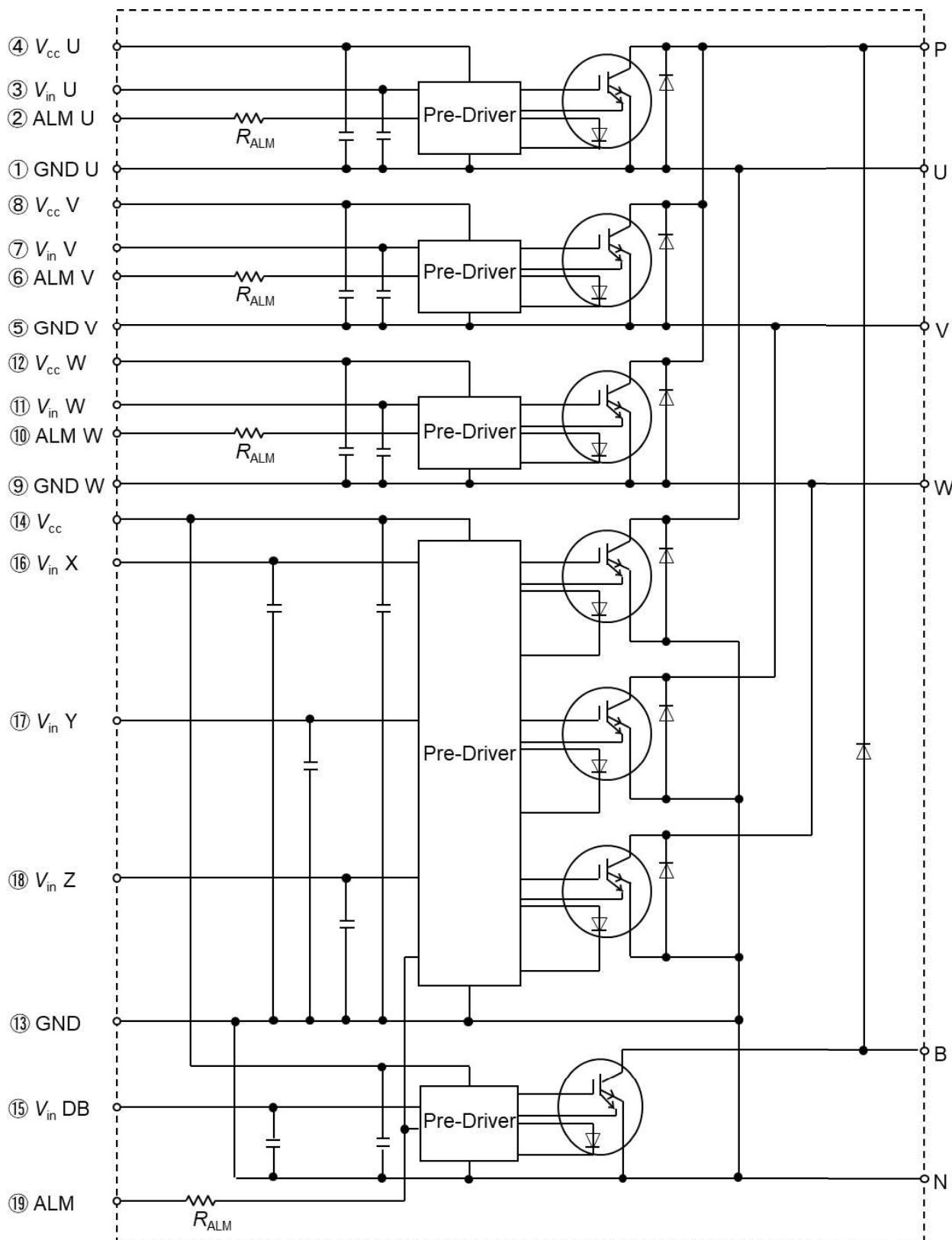
## ■ Noise immunity ( $V_{DC}=300V$ , $V_{CC}=15V$ )

Item	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width 1μs,polarity ±10min. Judge: no over-current, no miss operating	±2.0	-	-	kV

## ■ Recommended operating conditions

Item	Symbol	Min.	Typ.	Max.	Units
DC bus voltage	$V_{DC}$	-	-	800	V
Power supply voltage of pre-driver	$V_{CC}$	13.5	15.0	16.5	V
Switching frequency of IPM	$f_{sw}$	-	-	20.0	KHz
Arm shoot through blocking time for IPM's input signal *14	$t_{dead}$	1.5	-	-	μs
Screw torque (M4)	-	-	1.3	-	1.7
*14: $t_{dead} = t_{off} - t_{d(on)}$					

# 7MBP150XDN120-50

**IGBT Modules**
**■ Block diagram**


Pre-drivers include following functions

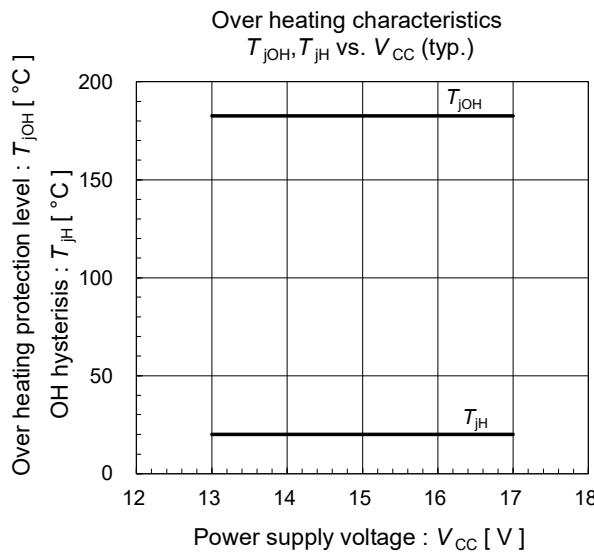
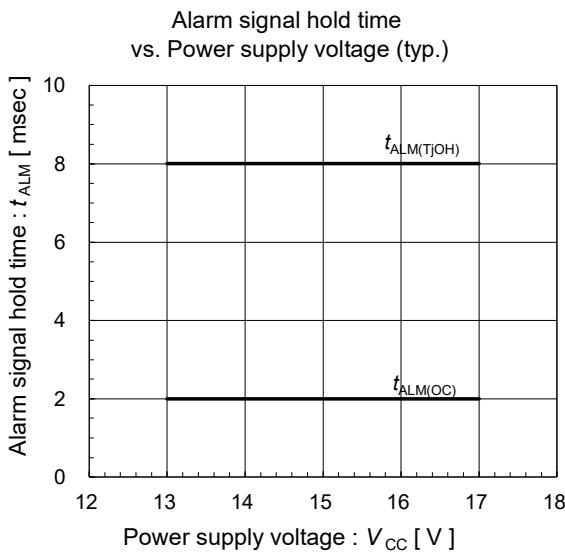
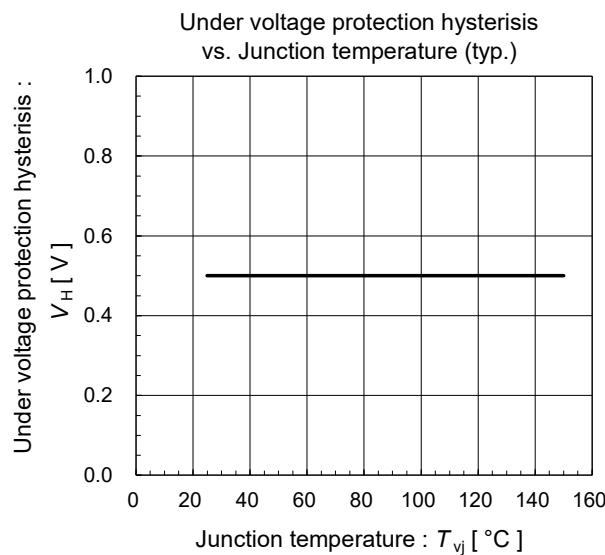
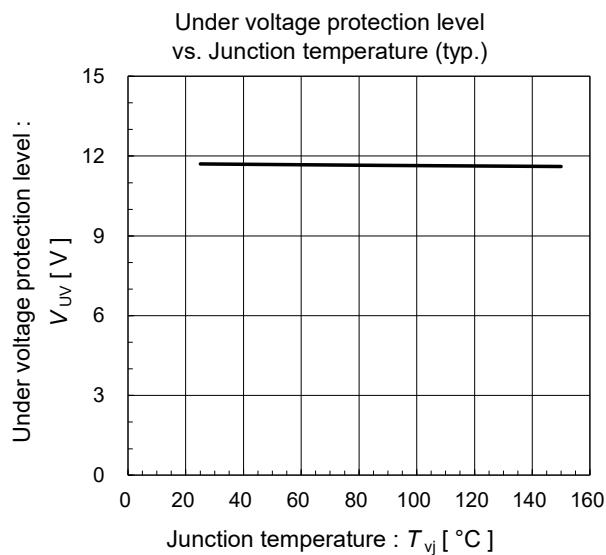
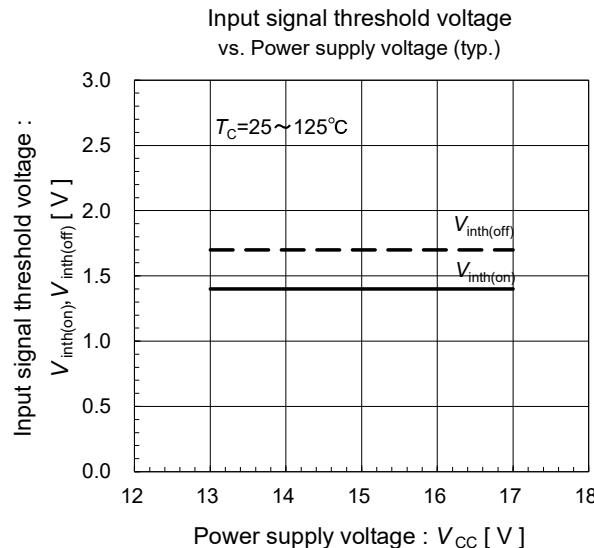
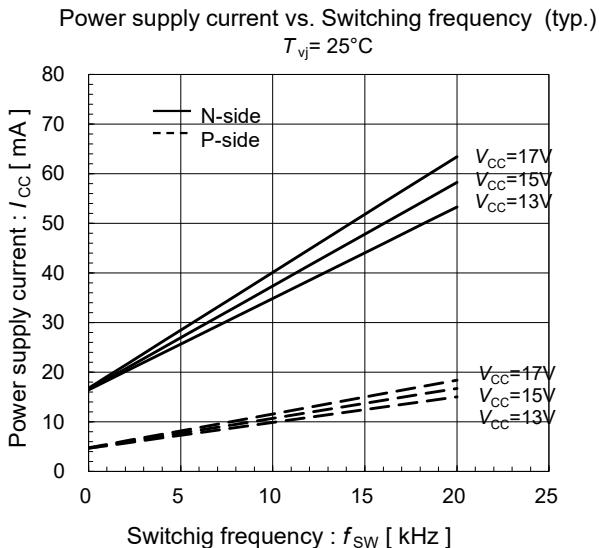
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

# 7MBP150XDN120-50

**IGBT Modules**

## ■ Characteristics (representative)

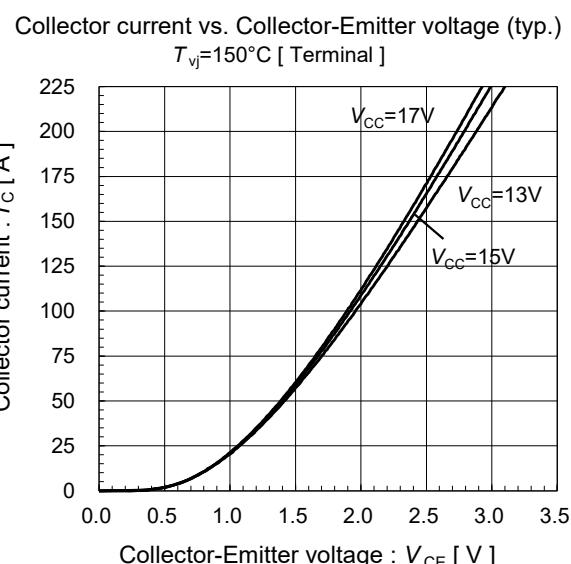
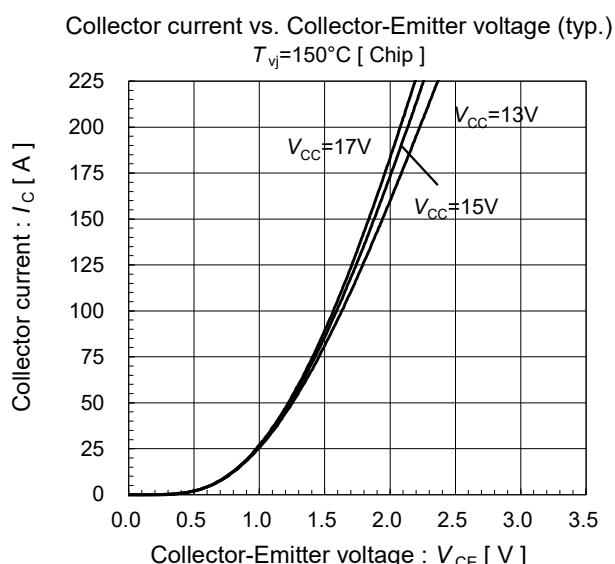
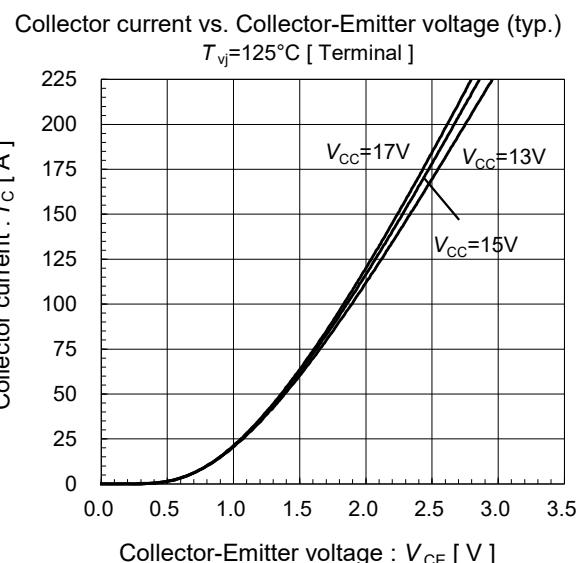
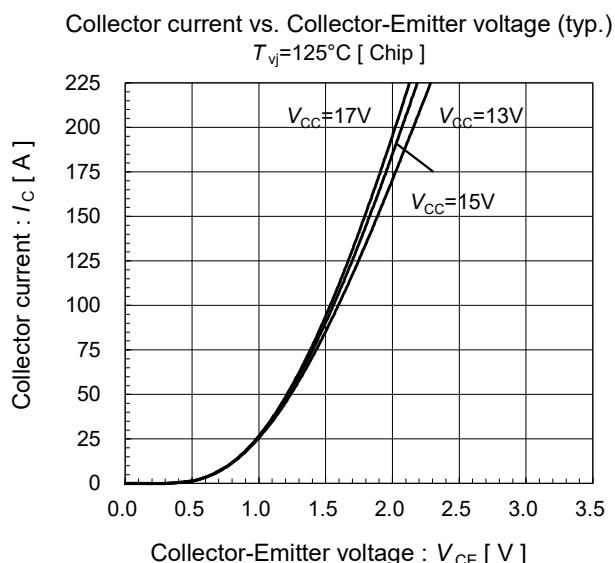
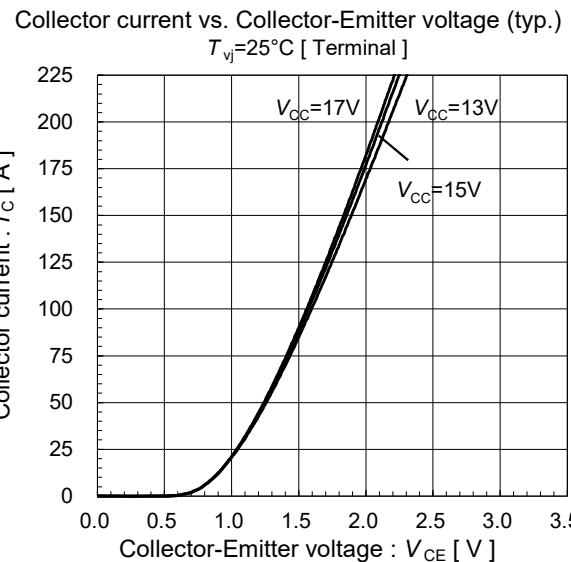
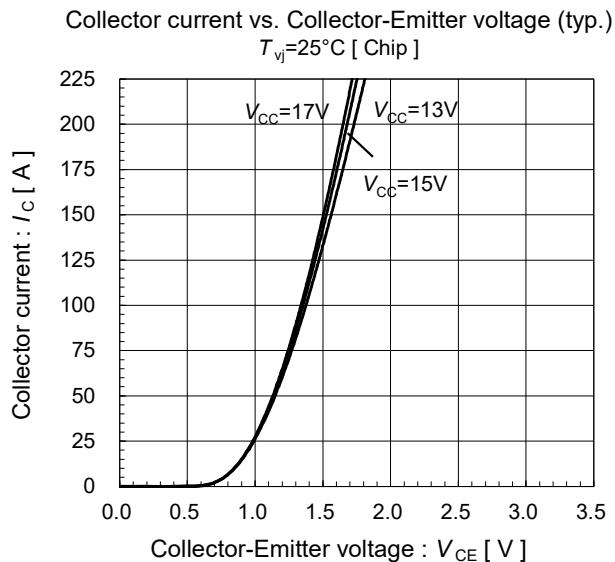
- Control circuit



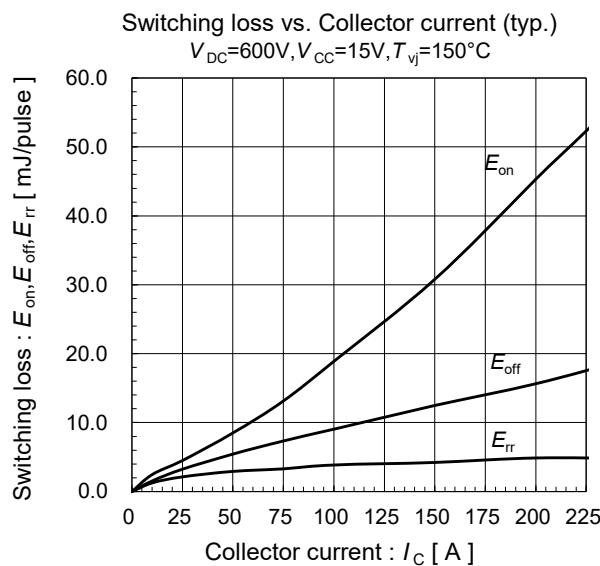
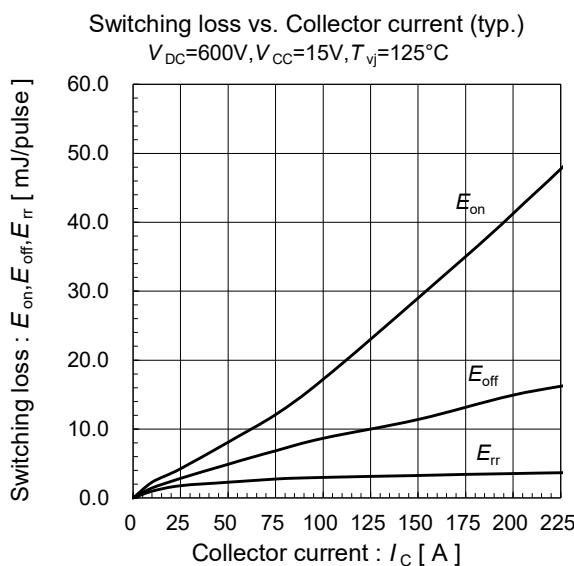
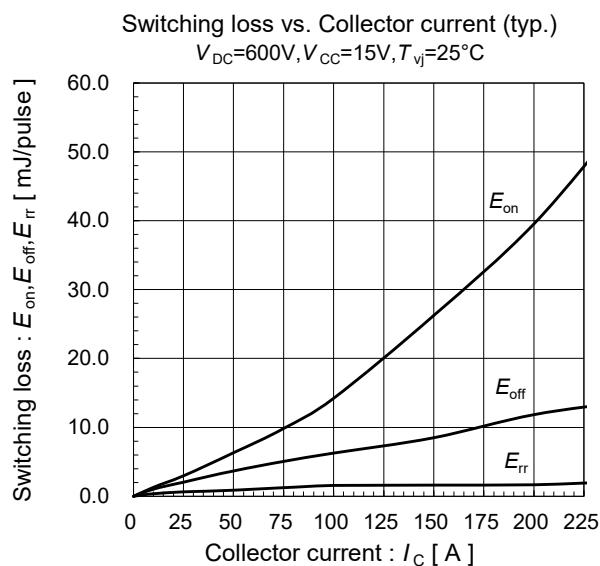
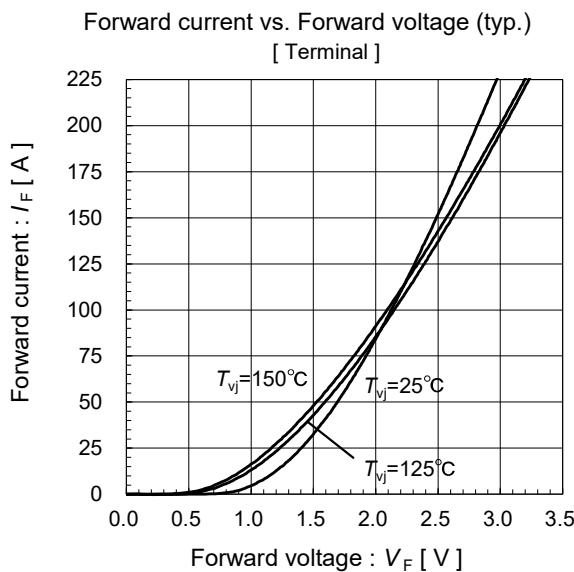
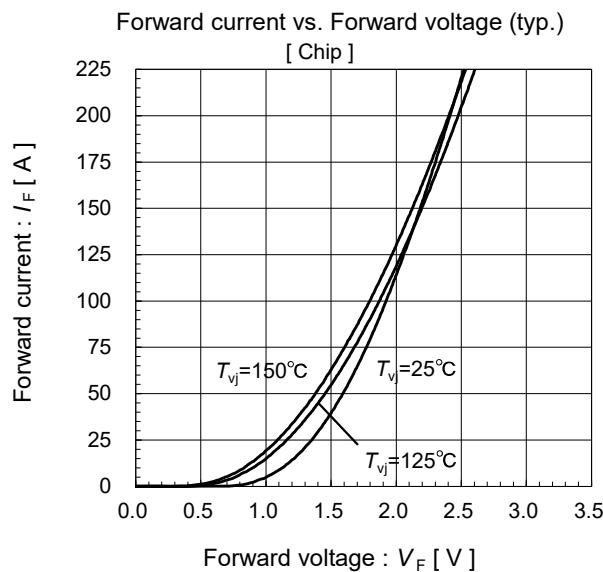
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**IGBT Modules**

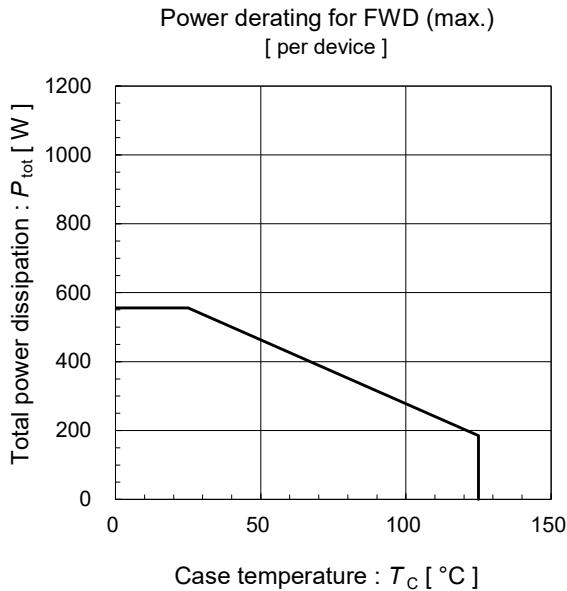
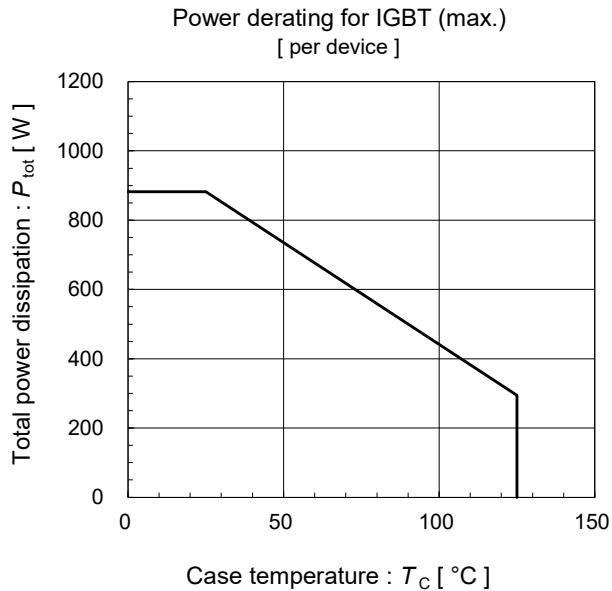
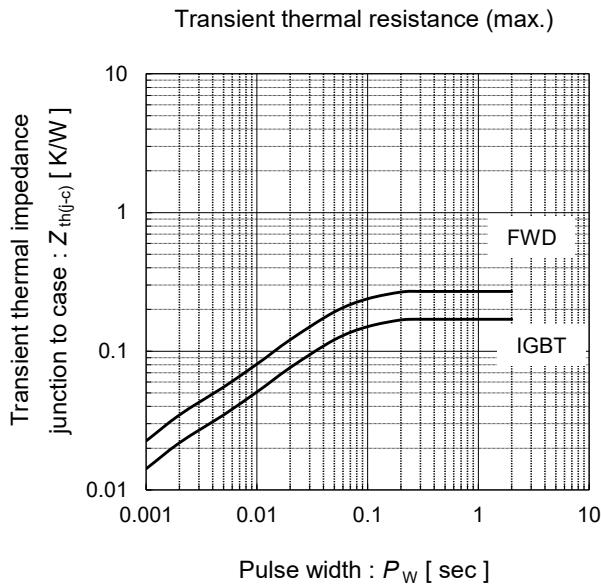
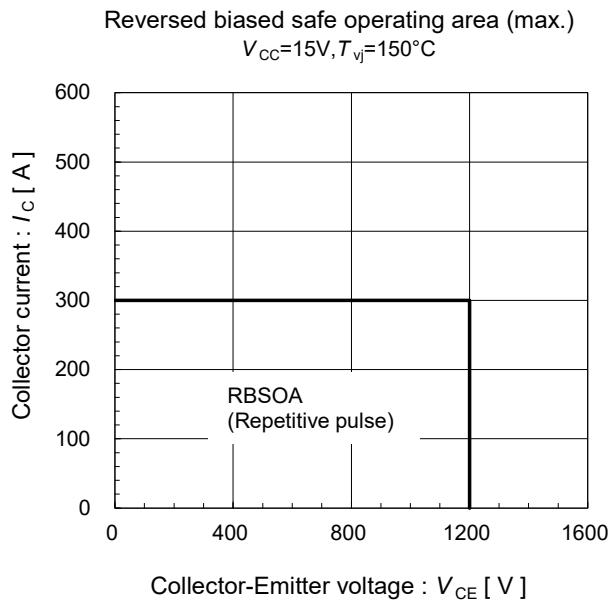
## ● Inverter



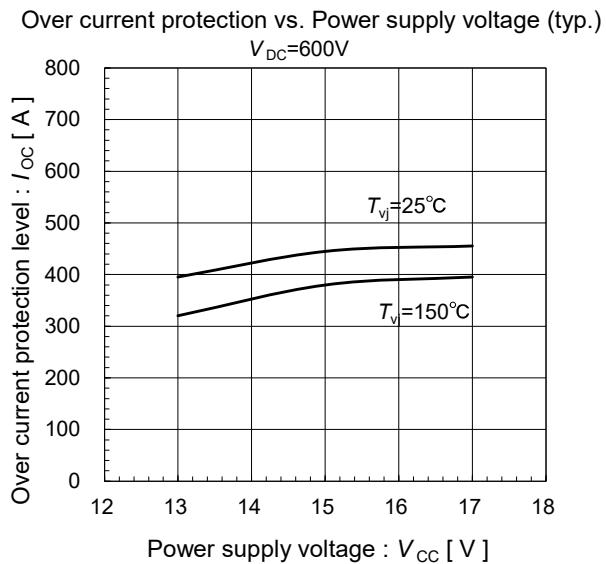
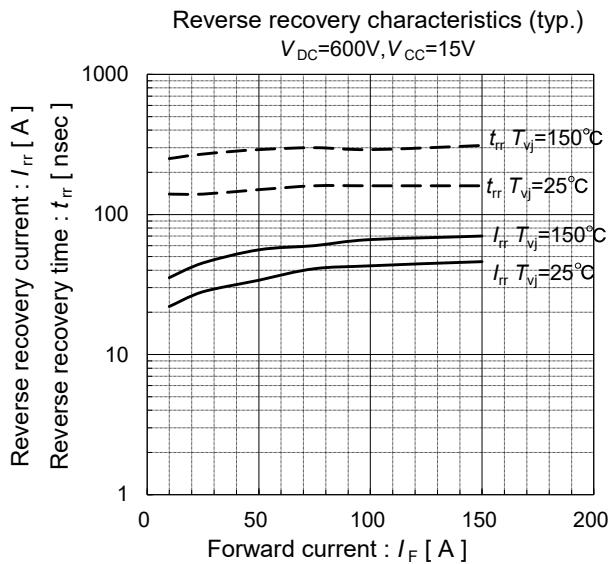
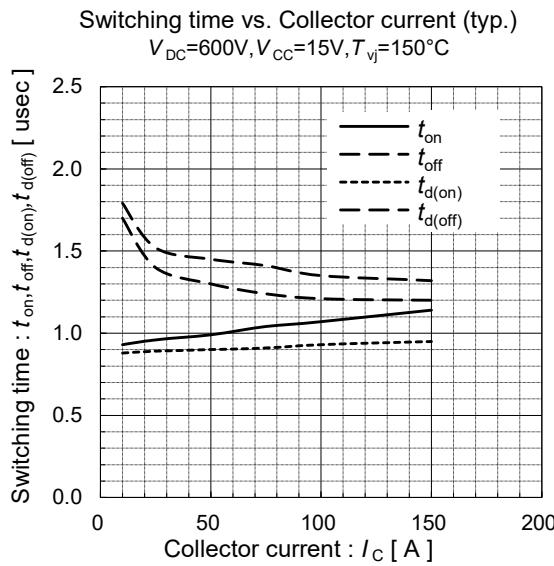
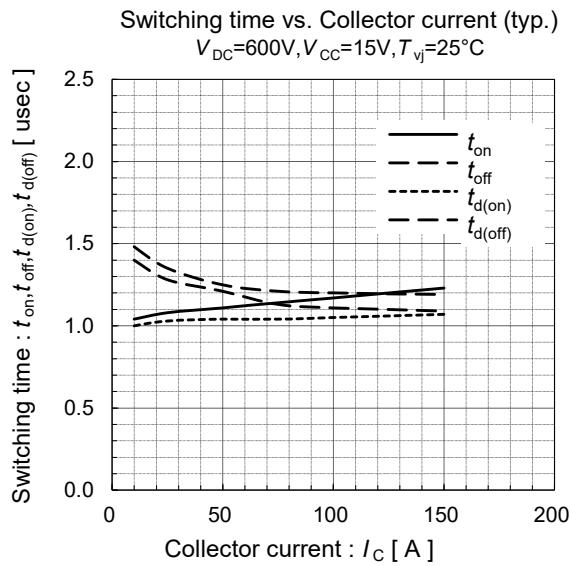
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**IGBT Modules**


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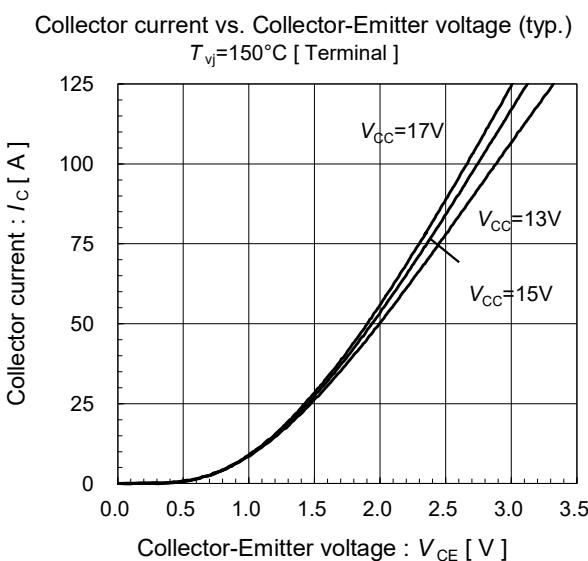
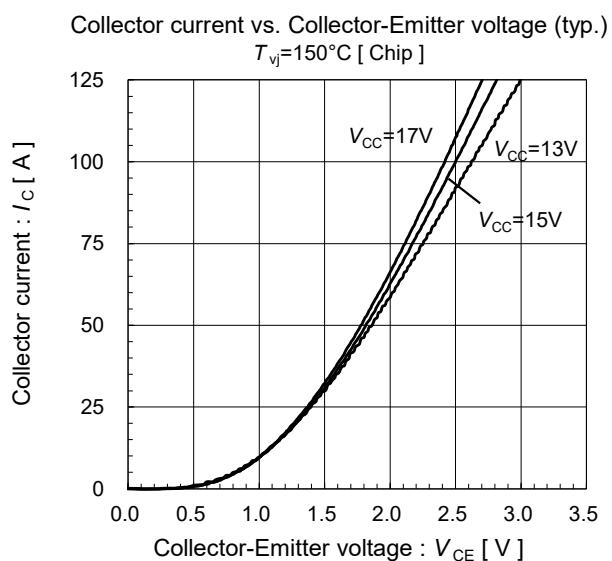
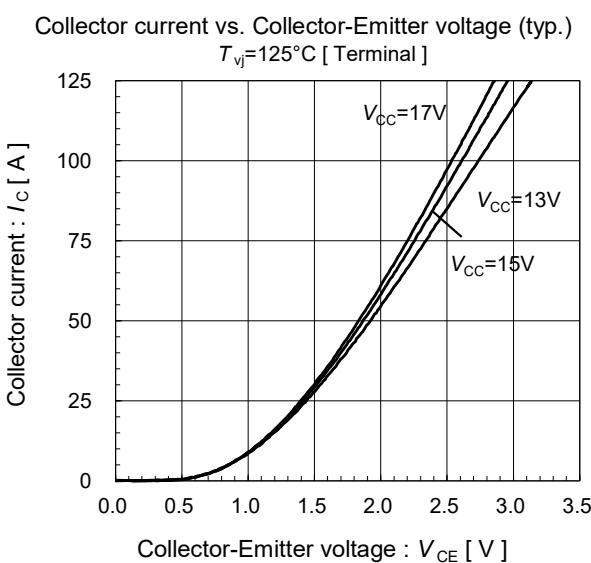
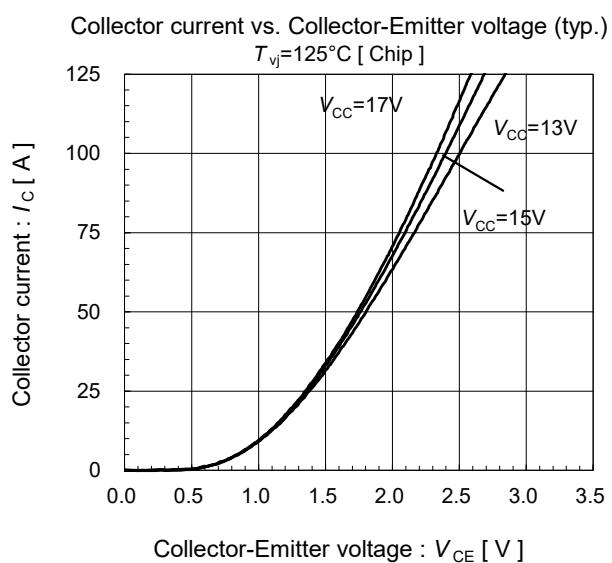
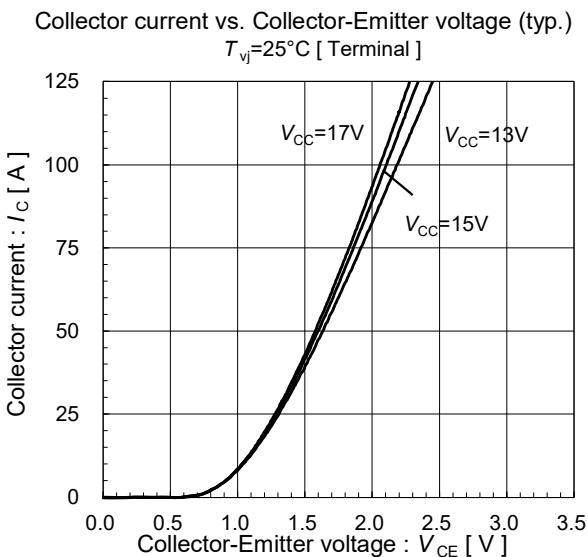
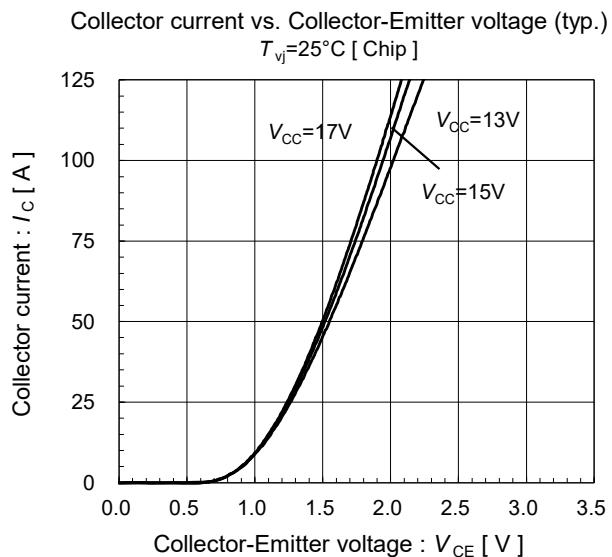
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**IGBT Modules**


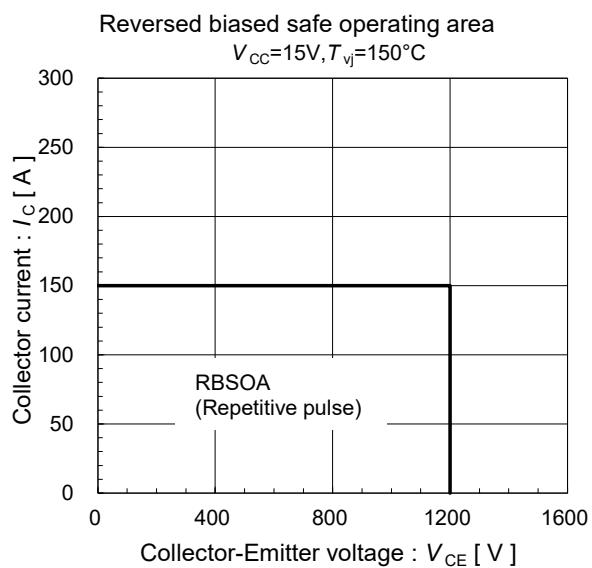
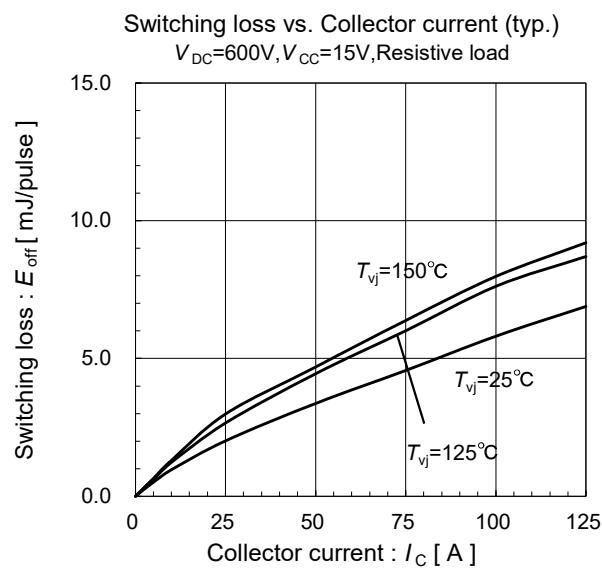
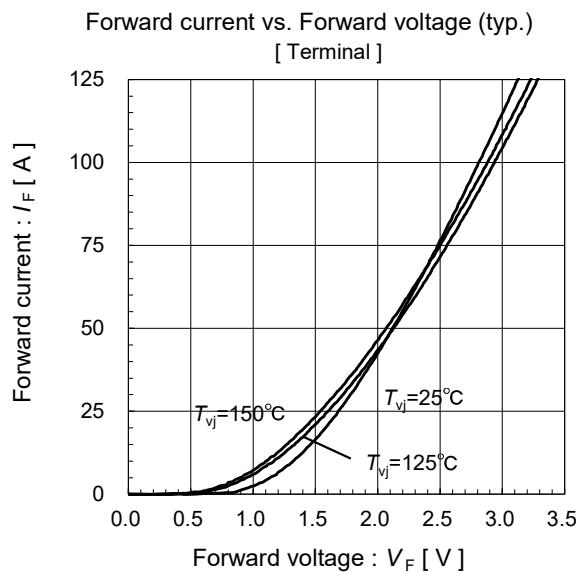
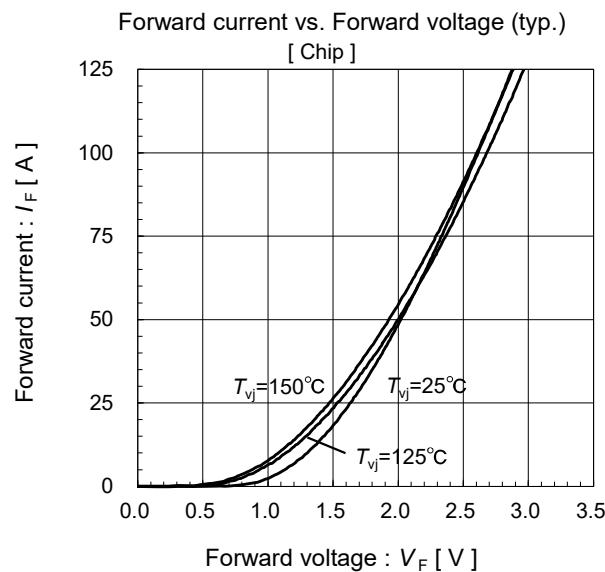
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**IGBT Modules**

## ● Brake

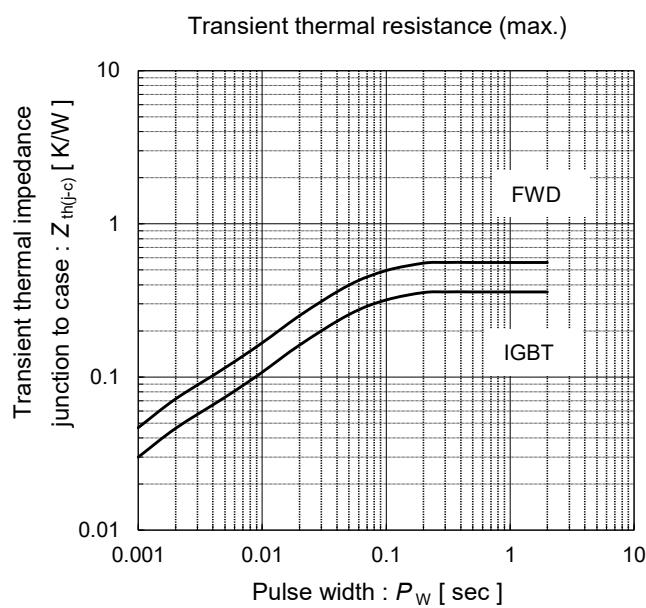
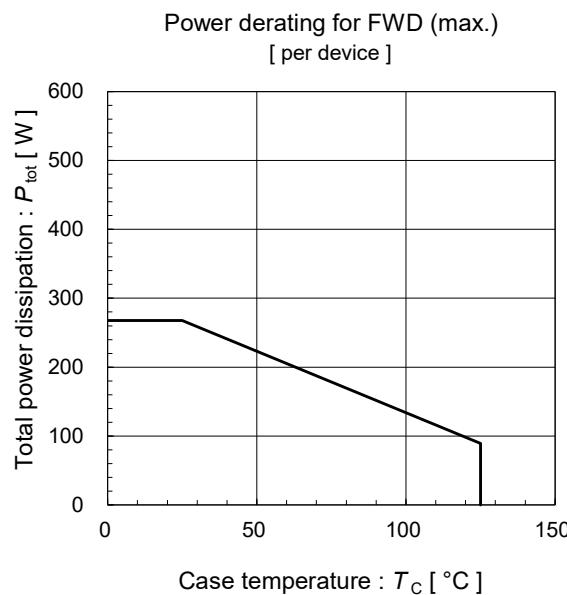
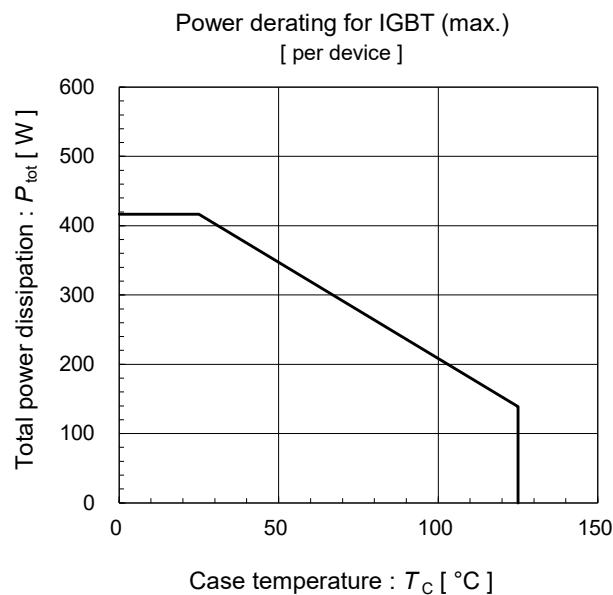


# 7MBP150XDN120-50

**IGBT Modules**


# 7MBP150XDN120-50

IGBT Modules



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日本	<a href="http://www.fujielectric.co.jp/products/semiconductor/">www.fujielectric.co.jp/products/semiconductor/</a>
Global	<a href="http://www.fujielectric.com/products/semiconductor/">www.fujielectric.com/products/semiconductor/</a>
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2 製品情報	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/">www.fujielectric.co.jp/products/semiconductor/model/</a>
3 アプリケーションマニュアル	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/application/">www.fujielectric.co.jp/products/semiconductor/model/igbt/application/</a>
4 デザインサポート	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/">www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/</a>
5 マウンティングインストラクション	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/">www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/</a>
6 IGBT 損失シミュレーションソフト	<a href="http://www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/">www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/</a>
7 富士電機技報	<a href="http://www.fujielectric.co.jp/products/semiconductor/journal/">www.fujielectric.co.jp/products/semiconductor/journal/</a>
8 製品のお問い合わせ	<a href="http://www.fujielectric.co.jp/products/semiconductor/contact/">www.fujielectric.co.jp/products/semiconductor/contact/</a>
9 改廃のお知らせ	<a href="http://www.fujielectric.co.jp/products/semiconductor/discontinued/">www.fujielectric.co.jp/products/semiconductor/discontinued/</a>

### Global

1 Semiconductors General Catalog	<a href="http://www.fujielectric.com/products/semiconductor/catalog/">www.fujielectric.com/products/semiconductor/catalog/</a>
2 Product Information	<a href="http://www.fujielectric.com/products/semiconductor/model/">www.fujielectric.com/products/semiconductor/model/</a>
3 Application Manuals	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/application/">www.fujielectric.com/products/semiconductor/model/igbt/application/</a>
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6 IGBT Loss Simulation Software	<a href="http://www.fujielectric.com/products/semiconductor/model/igbt/simulation/">www.fujielectric.com/products/semiconductor/model/igbt/simulation/</a>
7 Fuji Electric Journal	<a href="http://www.fujielectric.com/products/semiconductor/journal/">www.fujielectric.com/products/semiconductor/journal/</a>
8 Contact	<a href="http://www.fujielectric.com/contact/">www.fujielectric.com/contact/</a>
9 Revised and discontinued product information	<a href="http://www.fujielectric.com/products/semiconductor/discontinued/">www.fujielectric.com/products/semiconductor/discontinued/</a>

### 中国

1 半导体综合目录	<a href="http://www.fujielectric.com.cn/products/semiconductor/catalog/">www.fujielectric.com.cn/products/semiconductor/catalog/</a>
2 产品信息	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/">www.fujielectric.com.cn/products/semiconductor/model/</a>
3 应用手册	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/application/">www.fujielectric.com.cn/products/semiconductor/model/igbt/application/</a>
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5 安装说明书	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/">www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/</a>
6 IGBT 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/</a>
7 富士电机技报	<a href="http://www.fujielectric.com.cn/products/semiconductor/journal/">www.fujielectric.com.cn/products/semiconductor/journal/</a>
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